MOSFETs Silicon N-Channel MOS (DTMOSIV)

TK12E80W

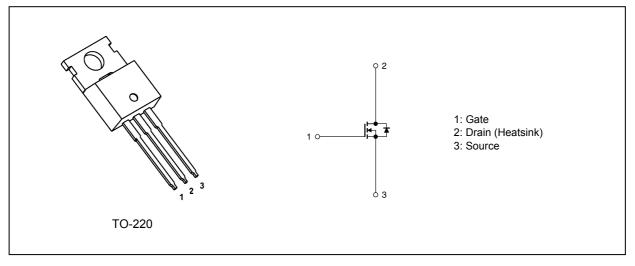
1. Applications

Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 0.38 \Omega$ (typ.) by using Super Junction Structure : DTMOS
- (2) Easy to control Gate switching
- (3) Enhancement mode: V_{th} = 3.0 to 4.0 V(V_{DS} = 10 V, I_D = 0.57 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	800	V
Gate-source voltage		V _{GSS}	±20	
Drain current (DC)	(Note 1)	I _D	11.5	A
Drain current (pulsed)	(Note 1)	I _{DP}	46	
Power dissipation $(T_c = 25^{\circ}C)$		PD	165	W
Single-pulse avalanche energy	(Note 2)	E _{AS}	326	mJ
Single-pulse avalanche current		I _{AS}	2.3	A
Reverse drain current (DC)	(Note 1)	I _{DR}	11.5	
Reverse drain current (pulsed)	(Note 1)	I _{DRP}	46	
Channel temperature		T _{ch}	150	°C
Storage temperature		T _{stg}	-55 to 150	
Mounting torque		TOR	0.6	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	0.757	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	83.3	

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: V_{DD} = 90 V, T_{ch} = 25 °C (initial), L = 112 mH, R_G = 25 Ω , I_{AS} = 2.3 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_	_	±1	μA
Drain cut-off current	I _{DSS}	V_{DS} = 800 V, V_{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	800	_	_	V
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.57 mA	3.0	_	4.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 5.8 A	_	0.38	0.45	Ω

6.2. Dynamic Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 300 V, V _{GS} = 0 V, f = 1 MHz	_	1400	—	pF
Reverse transfer capacitance	C _{rss}		_	3	_	
Output capacitance	C _{oss}		_	29	—	
Effective output capacitance	C _{o(er)}	V_{DS} = 0 to 640 V, V_{GS} = 0 V	_	35	_	
Gate resistance	r _g	V _{DS} = OPEN , f = 1 MHz	_	30	_	Ω
Switching time (rise time)	t _r	See Figure 6.2.1	_	40	—	ns
Switching time (turn-on time)	t _{on}		_	70	_	
Switching time (fall time)	t _f		_	11	_	
Switching time (turn-off time)	t _{off}			130	_	
MOSFET dv/dt ruggedness	dv/dt	$V_{DS} \le V_{(BR)DSS}$, $I_D \le 11.5 \text{ A}$	50		_	V/ns

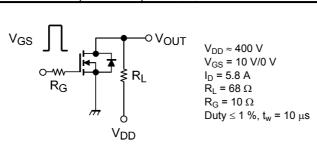


Fig. 6.2.1 Switching Time Test Circuit

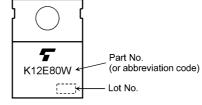
6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 640 \text{ V}, \text{ V}_{GS}$ = 10 V, I _D = 11.5 A	—	23	_	nC
Gate-source charge 1	Q _{gs1}		—	8	_	
Gate-drain charge	Q _{gd}		_	7.5	_	

6.4. Source-Drain Characteristics ($T_a = 25$ °C unless otherwise specified)

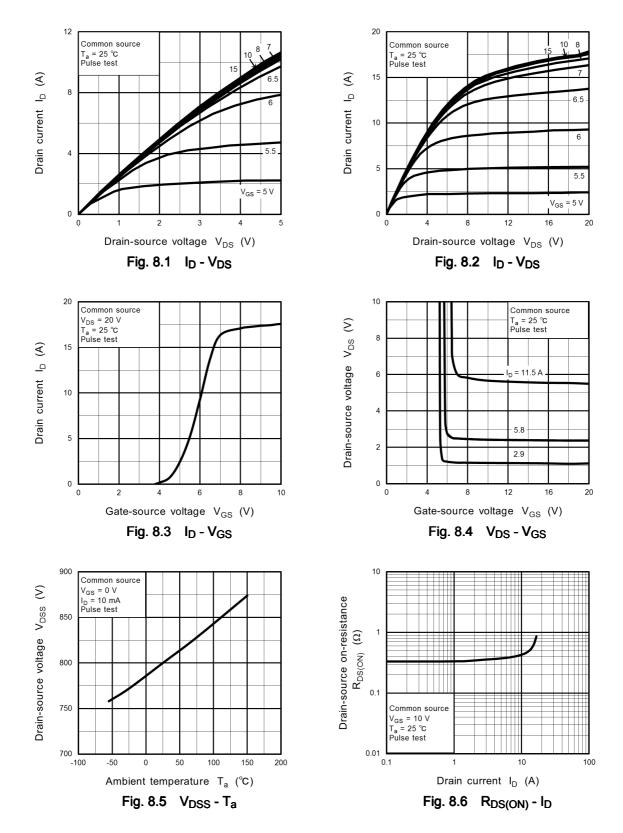
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V _{DSF}	I _{DR} = 11.5 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	V _{DD} ≈ 640 V	_	330	_	ns
Reverse recovery charge	Q _{rr}	I _{DR} = 5.8 A, V _{GS} = 0 V -dI _{DR} /dt = 100 A/µs	_	3.6	_	μC
Peak reverse recovery current	I _{rr}	$-di_{DR}/dt = 100 A/\mu s$	_	22	_	А
Diode dv/dt ruggedness	dv/dt	$V_{DS} \leq 640$ V, $I_{DR} \leq 5.8$ A, V_{GS} = 0 V	4.5			V/ns

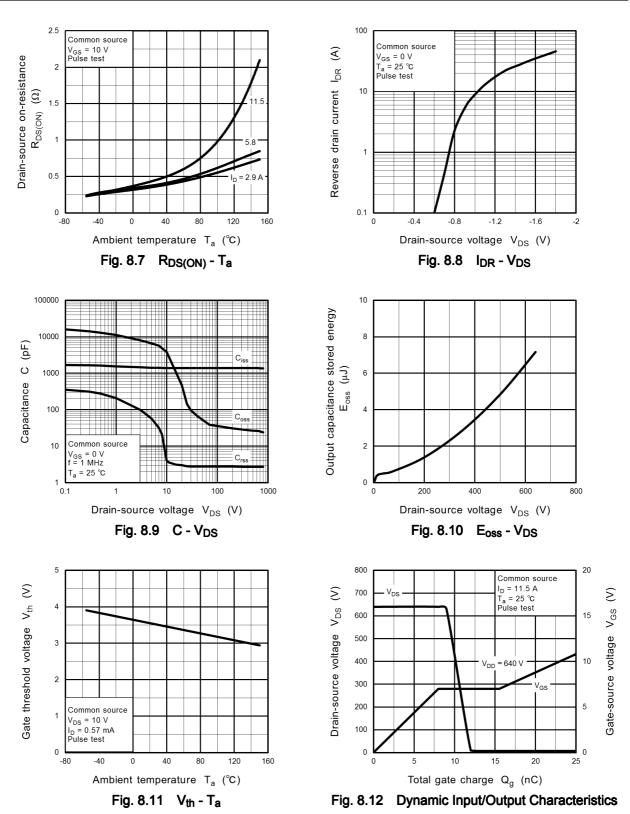
7. Marking





8. Characteristics Curves (Note)





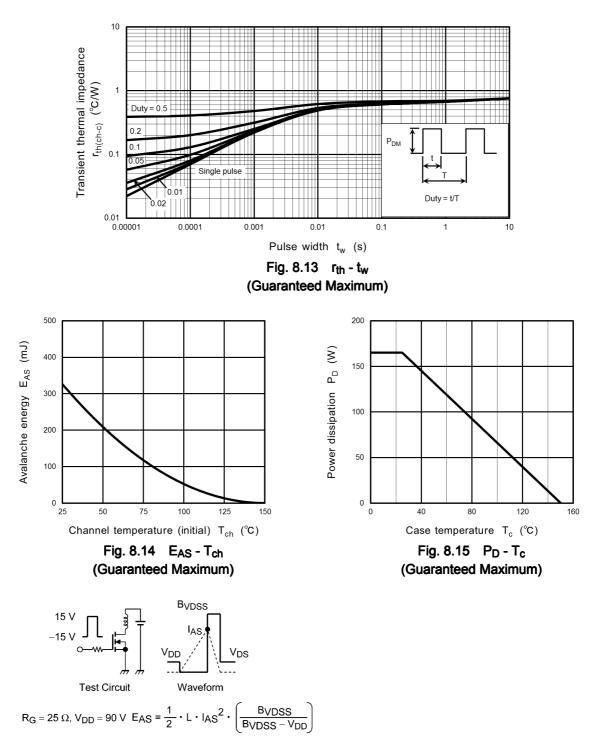
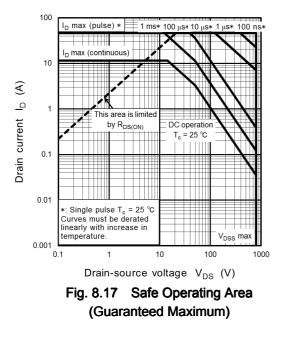


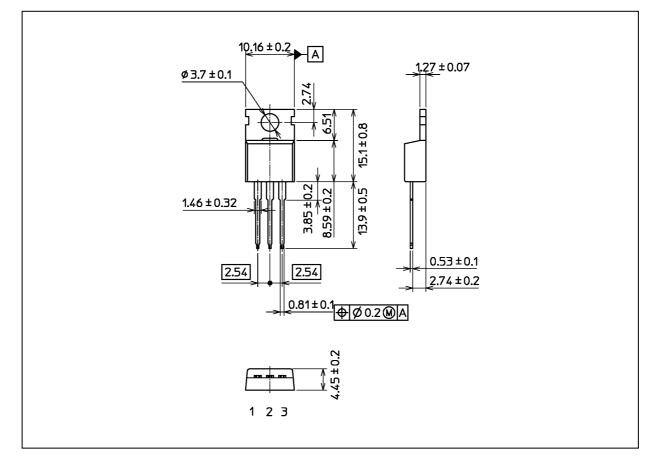
Fig. 8.16 Test Circuit/Waveform



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 1.93 g (typ.)

	Package Name(s)
TOSHIBA: 2-10X1A	
Nickname: TO-220	

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